

Rev. 3 — 11 June 2014

Product data sheet

1. Product profile

1.1 General description

The BGA7024 MMIC is a one-stage amplifier, available in a low-cost surface-mount package. It delivers 24 dBm output power at 1 dB gain compression and superior performance up to 2700 MHz.

1.2 Features and benefits

- 400 MHz to 2700 MHz frequency operating range
- 16 dB small signal gain at 2 GHz
- 24 dBm output power at 1 dB gain compression
- Integrated active biasing
- External matching allows broad application optimization of the electrical performance
- 5 V single supply operation
- All pins ESD protected

1.3 Applications

- Broadband CPE/MoCA
- WLAN/ISM/RFID
- Wireless infrastructure (base station, repeater, point-to-point backhaul systems)
- Industrial applications
- E-metering
- Satellite Master Antenna TV (SMATV)

1.4 Quick reference data

Table 1.Quick reference data

Input and output impedances matched to 50 Ω . Typical values at V_{CC} = 5 V; T_{case} = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CC}	supply current			95	110	125	mA
f	frequency		<u>[1]</u>	400	-	2700	MHz
G _p	power gain	f = 2140 MHz		13.5	15	16.5	dB
P _{L(1dB)}	output power at 1 dB gain compression	f = 2140 MHz		24.0	25.5	-	dBm
IP3 ₀	output third-order intercept point	f = 2140 MHz	[2]	35.0	38.5	-	dBm

[1] Operation outside this range is possible but not guaranteed.

[2] $P_L = 11 \text{ dBm per tone}$; spacing = 1 MHz.



Pinning information 2.

Pin	Description	S	implified outline	Graphic symbol
1	V _{CC(RF)}	[1]		~
2	GND	[2]		
3	RF_IN	<u>[1]</u>		sym130

[1] This pin is DC-coupled and requires an external DC-blocking capacitor.

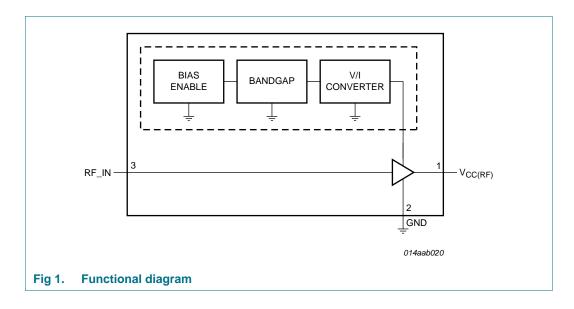
The center metal base of the SOT89 also functions as heatsink for the power amplifier. [2]

Ordering information 3.

Ordering information Table 3.

Type number	Package							
	Name	Description	Version					
BGA7024	-	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89					

Functional diagram 4.



Limiting values 5.

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(RF)}	RF supply voltage		-	5.7	V
P _{i(RF)}	RF input power		-	25	dBm
T _{case}	case temperature		-40	+85	°C
Tj	junction temperature		-	150	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E	-	2000	V
		Charged Device Model (CDM); according to JEDEC standard 22-C101B	-	500	V

Thermal characteristics 6.

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	[1][2]	25	K/W
		<u></u>	25	10.00

[1] Case is ground solder pad.

[2] Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air.

Static characteristics 7.

Table 6. **Characteristics**

Input and output impedances matched to 50 Ω . Typical values at V_{CC} = 5 V; T_{case} = 25 °C; unless otherwise specified.

Sy	mbol	Parameter	Conditions	Min	Тур	Max	Unit
V _C	C	supply voltage		-	5.0	-	V
I _{CC}	;	supply current		95	110	125	mA

Dynamic characteristics 8.

Table 7. **Dynamic characteristics**

Input and output impedances matched to 50 Ω . Typical values at V_{CC} = 5 V; T_{case} = 25 °C; see Section 12 "Application information"; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f	frequency	[1]	400	-	2700	MHz
G _p	power gain	f = 940 MHz	-	22	-	dB
		f = 1960 MHz	-	16	-	dB
		f = 2140 MHz	13.5	15	16.5	dB
		f = 2445 MHz	-	14	-	dB

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Table 7. I	Dynamic	characteristics	continued
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Input and output impedances matched to 50 Ω . Typical values at V_{CC} = 5 V; T_{case} = 25 °C; see Section 12 "Application information"; unless otherwise specified.

Symbol	Parameter	Conditions	Mir	Тур	Max	Unit
P _{L(1dB)}	output power at 1 dB gain compression	f = 940 MHz	-	24	-	dBm
		f = 1960 MHz	-	25.5	-	dBm
		f = 2140 MHz	24.	0 25.5	-	dBm
		f = 2445 MHz	-	24.5	-	dBm
IP3 ₀	output third-order intercept point	f = 940 MHz	2] -	37.5	-	dBm
		f = 1960 MHz	2] -	38.0	-	dBm
		f = 2140 MHz	2] 35.	38.0	-	dBm
		f = 2445 MHz	2] _	37.5	-	dBm
NF	noise figure	f = 940 MHz	3] _	2.9	-	dB
		f = 1960 MHz	3] _	3.7	-	dB
		f = 2140 MHz	3] _	3.7	-	dB
		f = 2445 MHz	3] -	4.0	-	dB
RL _{in}	input return loss	f = 940 MHz	-	-9	-	dB
		f = 1960 MHz	-	-10	-	dB
		f = 2140 MHz	-	-10	-	dB
		f = 2445 MHz	-	-14	-	dB
RL _{out}	output return loss	f = 940 MHz	-	-29	-	dB
		f = 1960 MHz	-	-22	-	dB
		f = 2140 MHz	-	-29	-	dB
		f = 2445 MHz	-	-11	-	dB

[1] Operation outside this range is possible but not guaranteed.

[2] $P_L = 11 \text{ dBm per tone}$; spacing = 1 MHz.

[3] Defined at $P_{i(RF)} = -40$ dBm; small signal conditions.

Scattering parameters 9.

Scattering parameters at 5 V, MMIC only Table 8.

f (MHz)	S ₁₁		S ₂₁	S ₂₁		S ₁₂		
	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)
400	0.83	-178.9	14.03	112.7	0.01	35.5	0.53	-166.3
500	0.85	178.7	11.69	104.4	0.01	38.77	0.56	-168.9
600	0.85	176.4	9.93	98.19	0.02	41.13	0.57	-172.2
700	0.86	173.8	8.67	93.04	0.02	43.1	0.58	-174.8
800	0.86	171.1	7.68	88.54	0.02	44.34	0.58	-177.4
900	0.86	168.3	6.9	84.36	0.02	44.96	0.59	179.7
1000	0.86	165.4	6.29	80.24	0.02	45.07	0.60	176.7
1100	0.87	162.7	5.72	76.42	0.02	45	0.60	173.3
1200	0.88	159.9	5.23	72.83	0.02	44.54	0.60	170.9
1300	0.88	157.3	4.80	69.34	0.03	44.17	0.61	168.4

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f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)
1400	0.89	154.8	4.43	66.17	0.03	43.58	0.61	166.4
1500	0.89	153	4.09	63.33	0.03	43.02	0.62	164.7
1600	0.89	151.3	3.80	60.8	0.03	42.67	0.63	163.1
1700	0.90	149.9	3.54	58.3	0.03	42.36	0.64	162.1
1800	0.90	148.7	3.30	56.13	0.03	41.89	0.65	161.2
1900	0.90	147.9	3.11	54.13	0.03	41.65	0.66	160.8
2000	0.91	147.5	2.93	52.63	0.03	41.7	0.66	160.5
2100	0.90	147	2.78	50.91	0.04	41.61	0.66	160.5
2200	0.90	146.9	2.65	49.5	0.04	41.59	0.67	160.9
2300	0.90	146.6	2.54	48.13	0.04	41.44	0.66	161.6
2400	0.90	146.5	2.46	46.88	0.04	41.61	0.66	161.7
2500	0.89	146.3	2.39	45.39	0.04	41.45	0.66	162.6
2600	0.88	146	2.34	43.93	0.05	41.13	0.65	162.8
2700	0.87	145.4	2.30	42.24	0.05	40.56	0.64	163.2

 Table 8.
 Scattering parameters at 5 V, MMIC only ...continued

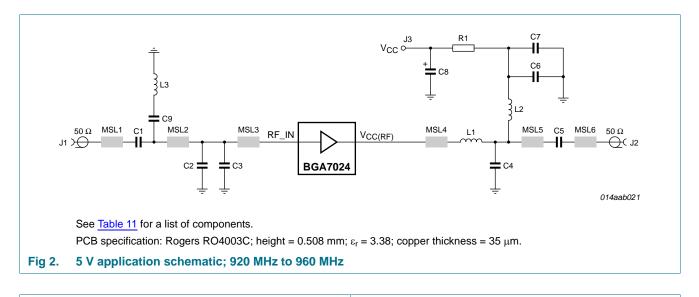
10. Reliability information

Table 9.	Reliability	
Life test	Conditions	Intrinsic failure rate
	according to JESD85; confidence level 60 %; $T_j = 55 \text{ °C}$; activation energy = 0.7 eV; acceleration factor according to Arrhenius equation	4

11. Moisture sensitivity

Table 10. Moisture sensitivity level	
Test methodology	Class
JESD-22-A113	1

12. Application information

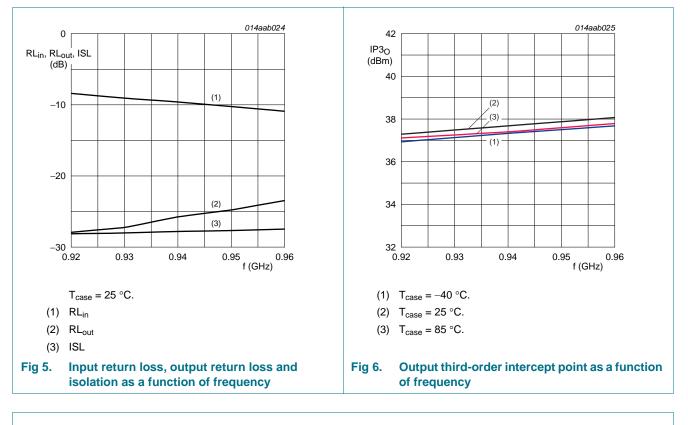


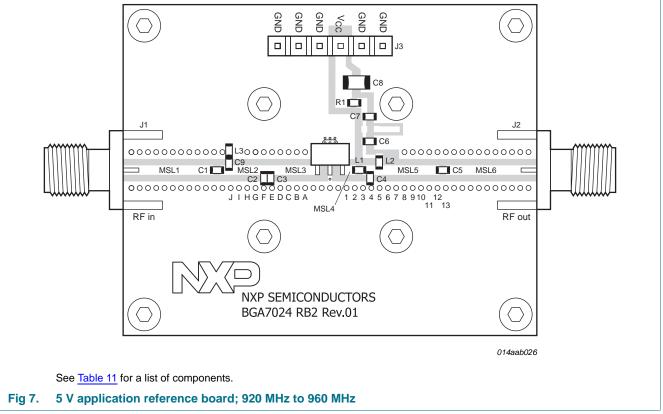
12.1 920 MHz to 960 MHz

014aab023 014aab022 28 30 P_{L(1dB)} (dBm) G_p (dB) 28 26 26 24 (1) (1) (2) (2) 22 24 (3) (3) 22 20 18 20 0.92 0.95 f (GHz) 0.93 0.93 0.94 0.92 0.94 0.95 0.96 0.96 f (GHz) (1) $T_{case} = -40 \ ^{\circ}C.$ (1) $T_{case} = -40 \ ^{\circ}C.$ (2) $T_{case} = 25 \ ^{\circ}C.$ (2) T_{case} = 25 °C. (3) $T_{case} = 85 \circ C$. (3) T_{case} = 85 °C. Output power at 1 dB gain compression as a Fig 4. Power gain as a function of frequency Fig 3. function of frequency

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400 MHz to 2700 MHz 0.25 W high linearity silicon amplifier





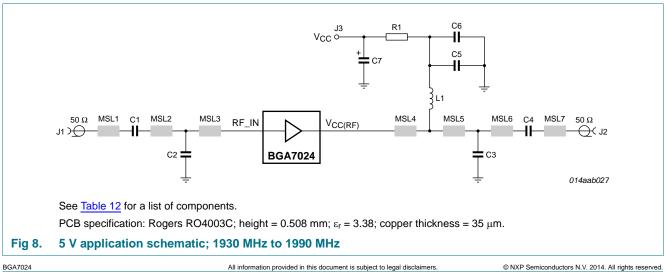
Component	Description	Value	Function	Remarks
C1, C5	capacitor	68 pF	DC blocking	Murata GRM1885C1H680JA01D
C2	capacitor	3.9 pF	input match	Murata GRM1885C1H3R9CZ01D
C3	capacitor	3.9 pF	input match	Murata GRM1885C1H3R9CZ01D
C4	capacitor	3.9 pF	output match	Murata GRM1885C1H3R9CZ01D
C6	capacitor	68 pF	RF decoupling	Murata GRM1885C1H680JA01D
C7	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C8	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
C9	capacitor	68 nF	IMD suppression	Murata GRM1888R71H683KA93D
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	4.7 nH	output match	Tyco Electronics 36501J4N7JTDG
L2	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
L3	inductor	33 nH	IMD suppression	Tyco Electronics 36501J033JTDG
MSL1[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm \times 0.8 mm \times 5.65 mm	input match	-
MSL3[1]	micro stripline	1.14 mm \times 0.8 mm \times 6.1 mm	input match	-
MSL4 <mark>[1]</mark>	micro stripline	1.14 mm \times 0.8 mm \times 1.6 mm	output match	-
MSL5[1]	micro stripline	1.14 mm \times 0.8 mm \times 8.4 mm	output match	-
MSL6[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
РСВ	-	RO4003C	-	-

Table 11. 5 V application list of components; 920 MHz to 960 MHz

See <u>Figure 2</u> and <u>Figure 7</u> for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating thickness = $35 \mu m$.

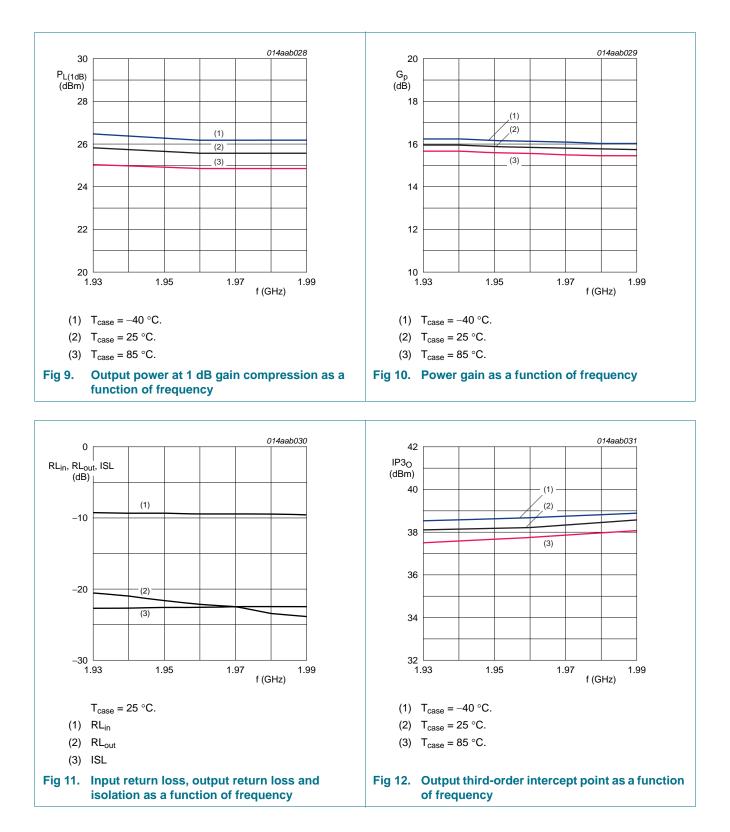
[1] MSL1 to MSL6 dimensions specified as width \times spacing \times length.

12.2 1930 MHz to 1990 MHz



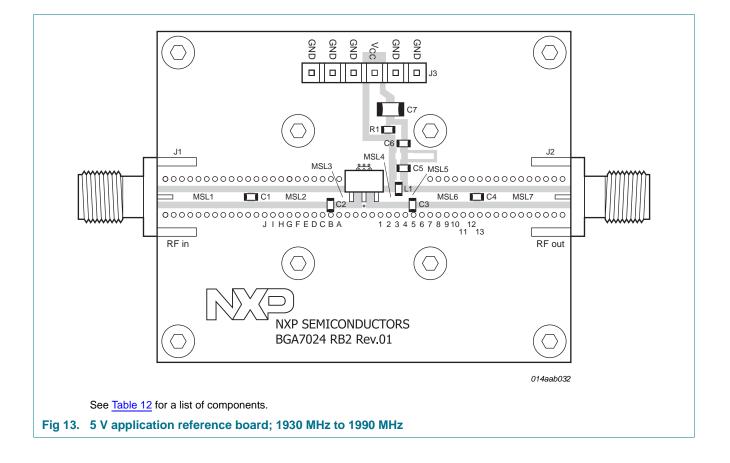
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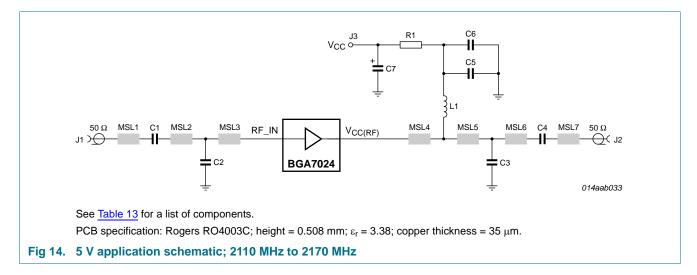


Component	Description	Value	Function	Remarks
C1, C4	capacitor	15 pF	DC blocking	Murata GRM1885C1H150JA01D
C2	capacitor	2.4 pF	input match	Murata GRM1885C1H2R4CZ01D
C3	capacitor	1.5 pF	output match	Murata GRM1885C1H1R5CZ01D
C5	capacitor	15 pF	RF decoupling	Murata GRM1885C1H150JA01D
C6	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C7	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
MSL1 ^[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm × 0.8 mm × 10.6 mm	input match	-
MSL3[1]	micro stripline	1.14 mm × 0.8 mm × 1.0 mm	input match	-
MSL4[1]	micro stripline	$1.14 \text{ mm} \times 0.8 \text{ mm} \times 2.7 \text{ mm}$	output match	-
MSL5[1]	micro stripline	$1.14 \text{ mm} \times 0.8 \text{ mm} \times 3.2 \text{ mm}$	output match	-
MSL6[1]	micro stripline	1.14 mm \times 0.8 mm \times 5.5 mm	output match	-
MSL7[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
PCB	-	RO4003C	-	-

Table 12. 5 V application list of components; 1930 MHz to 1990 MHz See <u>Figure 8</u> and <u>Figure 13</u> for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating thickness = $35 \mu m$.

[1] MSL1 to MSL7 dimensions specified as width \times spacing \times length.

12.3 2110 MHz to 2170 MHz



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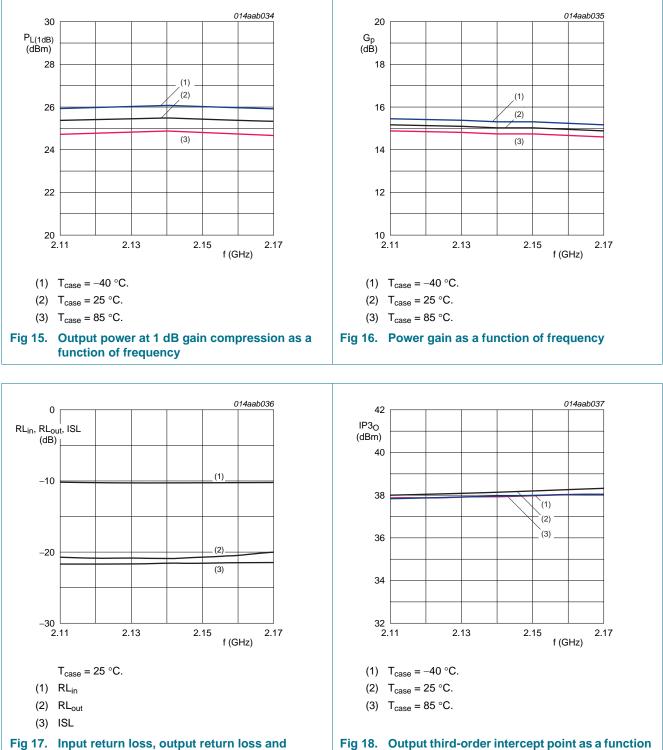


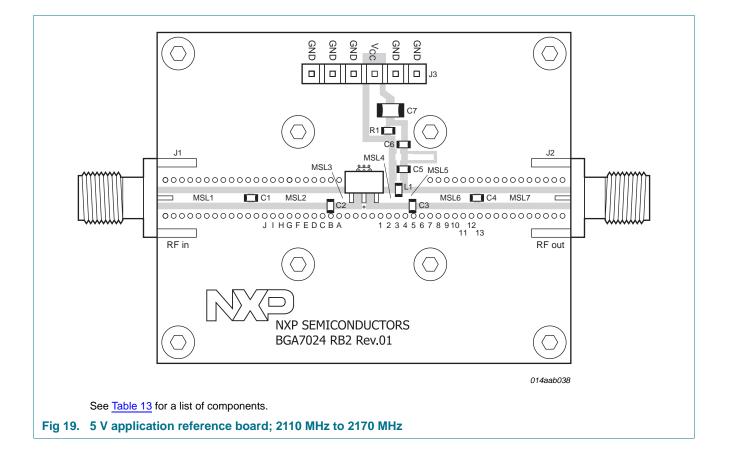
Fig 17. Input return loss, output return loss and isolation as a function of frequency



of frequency

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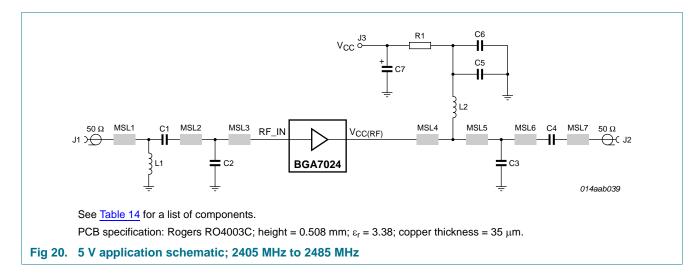


Component	Description	Value	Function	Remarks
C1, C4	capacitor	15 pF	DC blocking	Murata GRM1885C1H150JA01D
C2	capacitor	2.2 pF	input match	Murata GRM1885C1H2R2CZ01D
C3	capacitor	1.5 pF	output match	Murata GRM1885C1H1R5CZ01D
C5	capacitor	15 pF	RF decoupling	Murata GRM1885C1H150JA01D
C6	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C7	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
MSL1[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.6 mm	input match	-
MSL3[1]	micro stripline	1.14 mm \times 0.8 mm \times 1.0 mm	input match	-
MSL4 <mark>11</mark>	micro stripline	1.14 mm \times 0.8 mm \times 2.7 mm	output match	-
MSL5[1]	micro stripline	1.14 mm \times 0.8 mm \times 3.2 mm	output match	-
MSL6[1]	micro stripline	1.14 mm \times 0.8 mm \times 5.5 mm	output match	-
MSL7[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
РСВ	-	RO4003C	-	-

Table 13. 5 V application list of components; 2110 MHz to 2170 MHz See Figure 14 and Figure 19 for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating

[1] MSL1 to MSL7 dimensions specified as width × spacing × length.

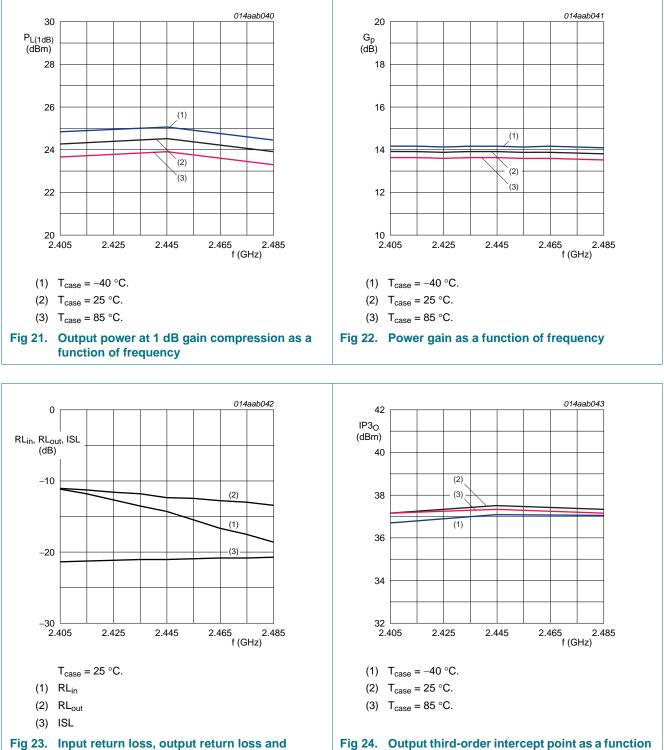
12.4 2405 MHz to 2485 MHz



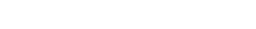
BGA7024 **Product data sheet**

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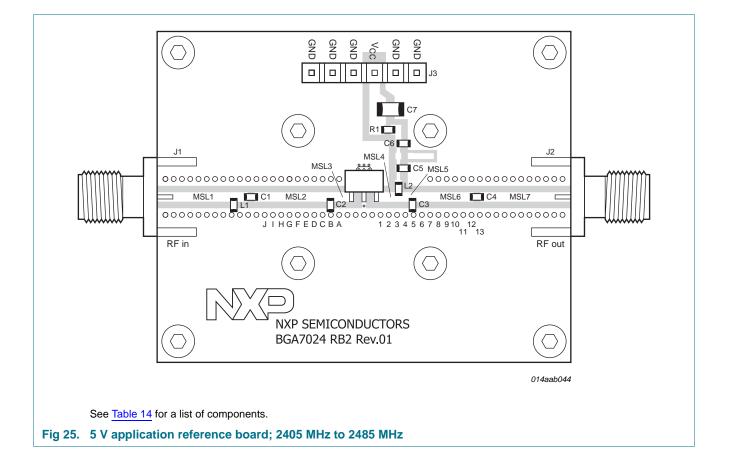
isolation as a function of frequency



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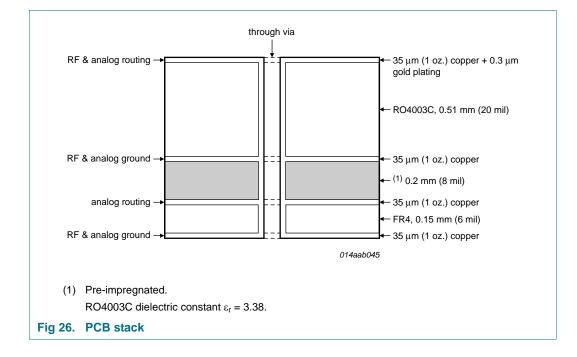


Component	Description	Value	Function	Remarks
C1, C4	capacitor	15 pF	DC blocking	Murata GRM1885C1H150JA01D
C2	capacitor	1.5 pF	input match	Murata GRM1885C1H1R5CZ01D
C3	capacitor	1.8 pF	output match	Murata GRM1885C1H1R8CZ01D
C5	capacitor	15 pF	RF decoupling	Murata GRM1885C1H150JA01D
C6	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C7	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	3.3 nH	input match	Tyco Electronics 36501J3N3JTDG
L2	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
MSL1[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	input match	-
MSL2 ^[1]	micro stripline	1.14 mm \times 0.8 mm \times 9.8 mm	input match	-
MSL3 ^[1]	micro stripline	1.14 mm \times 0.8 mm \times 1.9 mm	output match	-
MSL4[1]	micro stripline	1.14 mm \times 0.8 mm \times 2.5 mm	output match	-
MSL5 <mark>11</mark>	micro stripline	1.14 mm \times 0.8 mm \times 1.6 mm	output match	-
MSL6 ^[1]	micro stripline	1.14 mm \times 0.8 mm \times 7.3 mm	output match	-
MSL7[1]	micro stripline	1.14 mm \times 0.8 mm \times 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
PCB	-	RO4003C	-	-

Table 14. 5 V application list of components; 2405 MHz to 2485 MHz

See Figure 20 and Figure 25 for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating

[1] MSL1 to MSL7 dimensions specified as width \times spacing \times length.



12.5 PCB stack

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13. Package outline

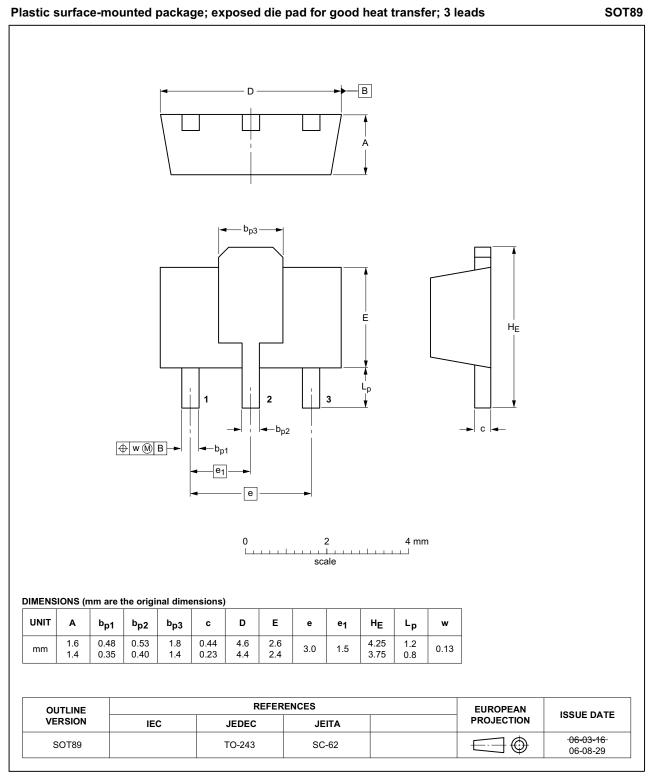


Fig 27. Package outline SOT89

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14. Abbreviations

Table 15. Abbreviations				
Acronym	Description			
CPE	Customer-Premises Equipment			
ESD	ElectroStatic Discharge			
HTOL	High Temperature Operating Life			
IR	InfraRed			
ISM	Industrial, Scientific and Medical			
MMIC	Monolithic Microwave Integrated Circuit			
MoCA	Multimedia over Coax Alliance			
PCB	Printed-Circuit Board			
RFID	Radio Frequency IDentification			
ТХ	Transmit			
WLAN	Wireless Local Area Network			

15. Revision history

Table 16. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA7024 v.3	20140611	Product data sheet	-	BGA7024 v.2
Modifications:	• Table 5 on page 3:	Thermal simulation results have b	peen replaced by IR measur	ements results.
BGA7024 v.2	20100830	Product data sheet	-	BGA7024 v.1
BGA7024	20100528	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

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